



# Fast CMOS 3.3V 16-Bit Register (3-State)

### **Product Features**

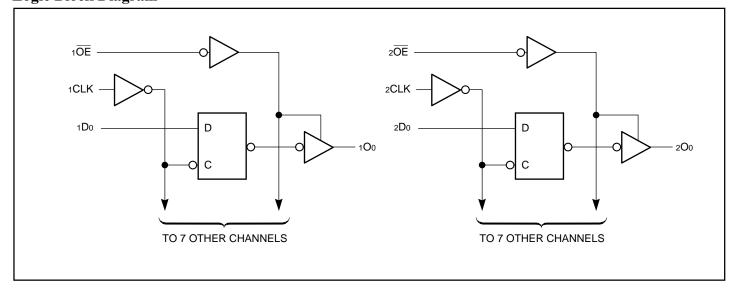
- Advanced Low Power CMOS Operation
- Can serve as a 5V to 3V translator
- Excellent output drive capability:
   Balanced drives (24 mA sink and source)
   Compatible with LVC<sup>TM</sup> class of products.
- Pin compatible with industry standard double-density pinouts
- Low ground bounce outputs
- Supports Live Insertion
- · Hysteresis on all inputs
- Industrial operating temperature range: -40°C to +85°C
- Inputs can be driven by 3.3V or 5V devices
- Multiple center pin and distributed Vcc/GND pins minimizing switching noise
- · Packages available:
  - -48-pin 240 mil wide plastic TSSOP (A)
  - -48-pin 300 mil wide plastic SSOP (V)
  - -48-pin 173 mil wide plastic TVSOP (K)

## **Product Description**

Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.6 micron CMOS technology, achieving industry leading speed grades.

The PI74FCT163374 is a 16-bit octal register designed with 16 D-type flip-flops with a buffered common clock and 3-state outputs. The Output Enable ( $\overline{\text{NOE}}$ ) and clock (xCLK) controls are organized to operate as two 8-bit registers or one 16-bit register. When  $\overline{\text{OE}}$  is HIGH, the outputs are in the high-impedance state. Input data meeting the setup and hold time requirements of the D inputs is transferred to the O outputs on the LOW-to-HIGH transition of the clock input.

# Logic Block Diagram



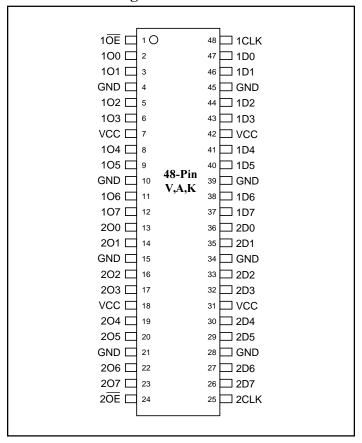
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# **Product Pin Description**

Pin Name	Description
xŌĒ	3-State Output Enable Inputs (Active LOW)
xCLK	Clock Inputs
xDx	Data Inputs
xOx	3-State Outputs
GND	Ground
Vcc	Power

# **Product Pin Configuration**



### **Truth Table**

		Inputs <sup>(1)</sup>	Outputs <sup>(1)</sup>	
Function	xDx	xCLK	x <del>OE</del>	xOx
High-Z	X	L	Н	Z
	X	Н	Н	Z
Load	L		L	L
Register	Н		L	Н
	L		Н	Z
	Н		Н	Z

#### Note:

- 1. H = High Voltage Level, X = Don't Care,
  - L = Low Voltage Level, Z = High Impedance

# Capacitance (TA = 25°C, f = 1 MHz)

Parameters <sup>(1)</sup>	Description	Test Conditions	Тур	Max.	Units
CIN	Input Capacitance	$V_{IN} = 0 V$	4.5	6	pF
Соит	Output Capacitance	$V_{OUT} = 0 V$	5.5	8	pF

### Note:

1. This parameter is determined by device characterization but is not production tested.



### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature—55°C to +125°C
Ambient Temperature with Power Applied40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only) $-0.5V$ to $+7.0V$
Supply Voltage to Ground Potential (Outputs & D/O Only) -0.5V to +7.0V
DC Input Voltage0.5V to +7.0V
DC Output Current
Power Dissipation

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **DC Electrical Characteristics** (Over the Operating Range, TA = -40°C to +85°C, VCC = 2.7V to 3.6V)

Parameters	Description	Test Conditions(1)		Min.	<b>Typ.</b> (2)	Max.	Units
Vih	Input HIGH Voltage (Input pins)	Guaranteed Logic HIGH Level		2.2	_	5.5	V
	Input HIGH Voltage (I/O pins)			2.0	_	Vcc+0.5	V
VIL	Input LOW Voltage	Guaranteed Logic LOW L	evel	-0.5	_	0.8	V
	(Input and I/O pins)						
Іін	Input HIGH Current (Input pins)	$V_{CC} = Max.$	$V_{IN} = 5.5V$	—		±1	μΑ
	Input HIGH Current (I/O pins)	$V_{CC} = Max.$	$V_{IN} = V_{CC}$	—		±1	μΑ
IIL	Input LOW Current (Input pins)	$V_{CC} = Max.$	$V_{IN} = GND$	_	_	±1	μΑ
	Input LOW Current (I/O pins)	$V_{CC} = Max.$	$V_{IN} = GND$			±1	μΑ
Іохн	High Impedance Output Current	$V_{CC} = Max.$	$V_{OUT} = V_{CC}$		_	±1	μΑ
Iozl	(3-State Output pins)	$V_{CC} = Max.$	$V_{OUT} = GND$	_	_	±1	μΑ
Vik	Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18mA$		-0.7	-1.2	V	
Iodh	Output HIGH Current	$V_{CC} = 3.3V$ , $V_{IN} = V_{IH}$ or $V_{IL}$ , $V_O = 1.5V^{(3)}$		-36	-60	-110	mA
Iodl	Output LOW Current	$V_{CC} = 3.3V$ , $V_{IN} = V_{IH}$ or	50	90	200	mA	
Voh	Output HIGH Voltage	$V_{CC} = Min.$	$I_{OH} = -0.1 \text{mA}$	Vcc-0.2	_	_	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -3mA$	2.4	3.0	_	V
		$V_{CC} = 3.0V$ ,	$I_{OH} = -8mA$	2.4(5)	3.0	_	V
		$V_{IN} = V_{IH OR} V_{IL}$	$I_{OH} = -24mA$	2.0	_	_	V
Vol	Output LOW Voltage	V <sub>CC</sub> = Min.	$I_{OL} = 0.1 mA$	_	_	0.2	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 16mA$	_	0.2	0.4	V
			$I_{OL} = 24mA$	_	0.3	0.5	V
Ios	Short Circuit Current <sup>(4)</sup>	$V_{CC} = Max.^{(3)}, V_{OUT} = GN$	1D		-60	-85	-240
mA							
VH	Input Hysteresis			_	150	_	mV

#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 3.3V,  $+25^{\circ}C$  ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. This parameter is guaranteed but not tested.
- 5. VOH = VCC 0.6V at rated current.



## **Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	<b>Typ.</b> <sup>(2)</sup>	Max.	Units
ICC	Quiescent Power Supply Current	VCC = Max.	VIN = GND or VCC		0.1	10	μΑ
ΔΙCC	Quiescent Power Supply Current TTL Inputs HIGH	VCC = Max.	$VIN = VCC - 0.6V^{(3)}$		2.0	30	μА
ICCD	Dynamic Power Supply <sup>(4)</sup>	VCC = Max., Outputs Open XOE = GND One Bit Toggling 50% Duty Cycle	VIN = VCC VIN = GND		50	75	μA/ MHz
IC	Total Power Supply Current <sup>(6)</sup>	VCC = Max., Outputs Open f1 = 10 MHZ 50% Duty Cycle XOE = GND One Bit Toggling	VIN = VCC - 0.6V VIN = GND		0.5	0.8	mA
		VCC = Max., Outputs Open ft = 2.5 MHZ 50% Duty Cycle xOE = GND 16 Bits Toggling	VIN = VCC - 0.6V VIN = GND		2.5	4.0 <sup>(5)</sup>	

#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at Vcc = 3.3V, +25°C ambient.
- 3. Per TTL driven input; all other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.
- 6. IC =IQUIESCENT + IINPUTS + IDYNAMIC
  - $IC = ICC + \Delta ICC DHNT + ICCD (fCP/2 + f1NI)$
  - ICC = Quiescent Current (ICCL, ICCH and ICCZ)
  - $\Delta$ ICC = Power Supply Current for a TTL High Input
  - DH = Duty Cycle for TTL Inputs High
  - NT = Number of TTL Inputs at DH
  - ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
  - fCP = Clock Frequency for Register Devices (Zero for Non-Register Devices)
  - NCP = Number of Clock Inputs at fCP
  - fl = Input Frequency
  - NI = Number of Inputs at fI
  - All currents are in milliamps and all frequencies are in megahertz.



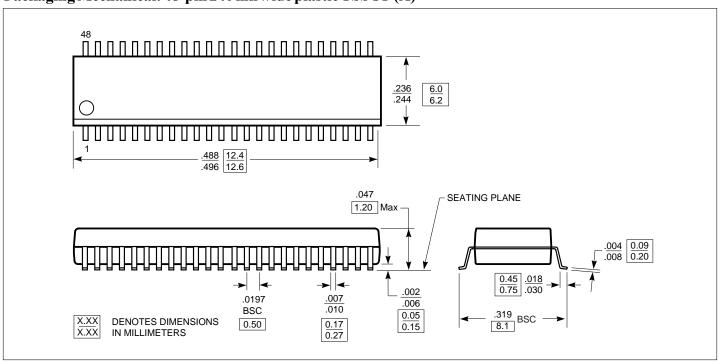
## Switching Characteristics over Operating Range<sup>(1)</sup>

			FCT1	63374	FCT16	63374A	FCT10	63374C	
			Com.		Com.		Com.		
Parameters	Description	Conditions <sup>(2)</sup>	Min. <sup>(3)</sup>	Max.	Min. <sup>(3)</sup>	Max.	Min. <sup>(3)</sup>	Max.	Units
tPLH tPHL	Propagation Delay xCLKtoxOx	CL=50pF RL=500ohm	2.0	10.0	2.0	6.5	2.0	5.2	ns
tPZH tPZL	Output Enable Time xOEtoxOx		1.5	12.5	1.5	6.5	1.5	5.5	ns
tPHZ tPLZ	Output Disable Time <sup>(4)</sup> xOEtoxOx		1.5	8.0	1.5	5.5	1.5	5.0	ns
tSU	Setup Time HIGH or LOW, xDx to xCLK		2.0		2.0		2.0		ns
tH	HoldTimeHIGH or LOW, xDx to xCLK		1.5		1.5		1.5		ns
tW	xCLK Pulse Width HIGH <sup>(4)</sup>		7.0		5.0		5.0		ns
tSK(o)	Output Skew <sup>(5)</sup>			0.5		0.5		0.5	ns

#### **Notes:**

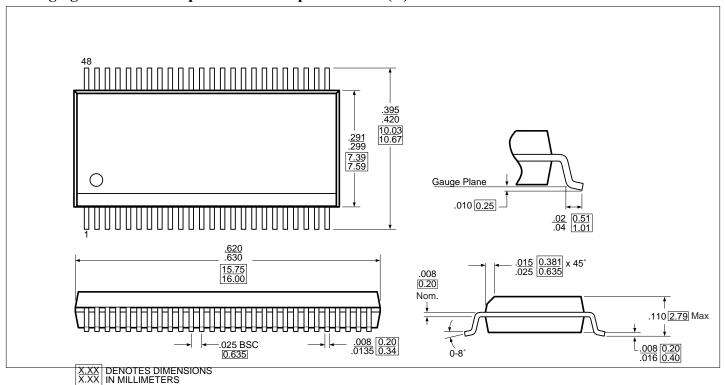
- 1. Propagation Delays and Enable/Disable times are with  $Vcc = 3.3V \pm 0.3V$ , normal range. For Vcc = 2.7V, extended range, all Propagation Delays and Enable/Disable times should be degraded by 20%.
- 2. See test circuit and wave forms.
- 3. Minimum limits are guaranteed but not tested on Propagation Delays.
- 4. This parameter is guaranteed but not production tested.
- 5. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.

### Packaging Mechanical: 48-pin 240 mil wide plastic TSSOP (A)

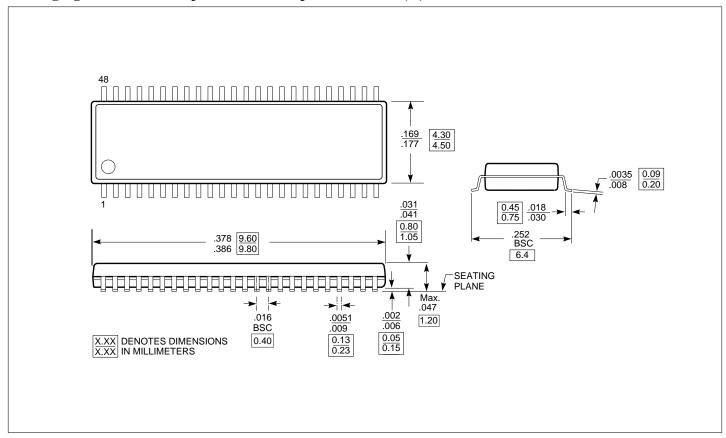




## Packaging Mechanical: 48-pin 300 mil wide plastic SSOP (V)



# Packaging Mechanical: 48-pin 173 mil wide plastic TVSOP (K)





# **Ordering Information**

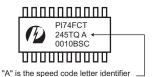
Part	Operating Range
PI74FCT163374A	48-pin 240 mil wide plastic TSSOP (A)
PI74FCT163374V	48-pin 300 mil wide plastic SSOP (V)
PI74FCT163374K	48-pin 173 mil wide plastic TVSOP (B)

### **Part Marking Information**

Pericom s standard product mark follows our standard part number ordering information, except for those products with a speed letter code. For marking purposes, the speed letter code mark is placed after the package code letter, rather than after the device number as it is ordered.

Although all products are marked immediately after assembly to assure material traceability, Pericom does not usually mark the speed code at that time. After electrical test screening and speed binning has been completed, we then perform an add mark operation which places the speed code letter at the end of the complete part number.

Please refer to the example shown below: Part Number as ordered: PI74FCT245ATQ Example of Part Number as marked:



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1) 8-pin DIP, 8-pin SOIC, 8-pin TSSOP, 14-pin SOIC, 16-pin QSOP, SC70, MSOP, and SOT23 packages are not marked with the Pericom logo due to space limitations on the package.